NSN 5961-01-186-2369

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-186-2369 **Inclosure Material:** Plastic **Overall Length:** Between 0.730 inches and 0.830 inches **Overall Diameter:** 1.900 inches **Mounting Facility Quantity: Mounting Method:** Threaded hole and threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5000.0 working peak reverse voltage **Current Rating Per Characteristic:** 4.50 amperes collector current, dc absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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